

## Extra Fast Recovery Diode

### Types F1300N#45P to F1300N#55P

#### Absolute Maximum Ratings

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
$V_{RRM}$	Repetitive peak reverse voltage, (note 1)	4500-5500	V
$V_{RSM}$	Non-repetitive peak reverse voltage, (note 1)	4600-5600	V
$V_{R(d.c.)}$	Maximum reverse d.c. voltage (note 1)	2300-2800	V

	OTHER RATINGS (note 6)	MAXIMUM LIMITS	UNITS
$I_{F(AV)M}$	Mean forward current, $T_{sink}=55^{\circ}C$ , (note 2)	1346	A
$I_{F(AV)M}$	Mean forward current. $T_{sink}=100^{\circ}C$ , (note 2)	767	A
$I_{F(AV)M}$	Mean forward current. $T_{sink}=100^{\circ}C$ , (note 3)	435	A
$I_{F(RMS)}$	Nominal RMS forward current, $T_{sink}=25^{\circ}C$ , (note 2)	2615	A
$I_{F(d.c.)}$	D.C. forward current, $T_{sink}=25^{\circ}C$ , (note 4)	2130	A
$I_{FSM}$	Peak non-repetitive surge $t_p=10ms$ , $V_{RM}=60\%V_{RRM}$ , (note 5)	20.8	kA
$I_{FSM2}$	Peak non-repetitive surge $t_p=10ms$ , $V_{RM}\leq 10V$ , (note 5)	22.9	kA
$I^2t$	$I^2t$ capacity for fusing $t_p=10ms$ , $V_{RM}=60\%V_{RRM}$ , (note 5)	$2.16\times 10^6$	$A^2s$
$I^2t$	$I^2t$ capacity for fusing $t_p=10ms$ , $V_{RM}\leq 10V$ , (note 5)	$2.62\times 10^6$	$A^2s$
$T_{j\ op}$	Operating temperature range	-40 to +140	$^{\circ}C$
$T_{stg}$	Storage temperature range	-40 to +140	$^{\circ}C$

Notes:-

- 1) De-rating factor of 0.13% per  $^{\circ}C$  is applicable for  $T_j$  below  $25^{\circ}C$ .
- 2) Double side cooled, single phase; 50Hz,  $180^{\circ}$  half-sinewave.
- 3) Single side cooled, single phase; 50Hz,  $180^{\circ}$  half-sinewave.
- 4) Double side cooled.
- 5) Half-sinewave,  $140^{\circ}C$   $T_j$  initial.
- 6) Current ( $I_F$ ) ratings have been calculated using  $V_{T0}$  and  $r_T$  (see page 2)

**Characteristics**

	PARAMETER	MIN.	TYP.	MAX.	TEST CONDITIONS (Note 1)	UNITS
V <sub>FM</sub>	Maximum peak forward voltage	-	-	1.75 1.95	I <sub>FM</sub> = 800A I <sub>FM</sub> = 1200A	V
V <sub>T0</sub>	Threshold voltage	-	-	1.569	Over current range 1346 – 4038A (Note 2)	V
r <sub>T</sub>	Slope resistance	-	-	0.318		mΩ
V <sub>T01</sub>	Threshold voltage	-	-	1.539	Over current range 1200 – 3600A	V
r <sub>T1</sub>	Slope resistance	-	-	0.332		mΩ
V <sub>FRM</sub>	Maximum forward recovery voltage	-	-	120 230	di/dt = 1000A/μs, 25°C di/dt = 1000A/μs	V
I <sub>RRM</sub>	Peak reverse current	-	-	40 10	Rated V <sub>RRM</sub> Rated V <sub>RRM</sub> , T <sub>j</sub> =25°C	mA
Q <sub>rr</sub>	Recovered charge	-	2150	-	I <sub>FM</sub> =1000A, t <sub>p</sub> =1000μs, di/dt=200A/μs, V <sub>r</sub> =100V, 50% Chord (note 3)	μC
Q <sub>ra</sub>	Recovered charge, 50% Chord	-	1010	1300		μC
I <sub>rm</sub>	Reverse recovery current	-	470	-		A
t <sub>rr</sub>	Reverse recovery time, 50% Chord	-	4.3	-		μs
Q <sub>rr</sub>	Recovered charge	-	4680	-	I <sub>FM</sub> =1200A, t <sub>p</sub> =1000μs, di/dt=200A/μs, V <sub>r</sub> =1500V, with 4.5Ω, 1μF snubber (Note 3)	μC
Q <sub>ra</sub>	Recovered charge, 50% Chord	-	3680	4100		μC
I <sub>rm</sub>	Reverse recovery current	-	560	-		A
t <sub>rr</sub>	Reverse recovery time, 50% Chord	-	15	-		μs
R <sub>thJK</sub>	Thermal resistance, junction to heatsink (note 4)	-	-	0.024 0.048	Double side cooled Anode side cooled	K/W
F	Mounting force	19	-	26	(Note 4)	kN
W <sub>t</sub>	Weight	-	510	-		g

**Notes:-**

- 1) Unless otherwise indicated T<sub>j</sub>=140°C.
- 2) V<sub>T0</sub> and r<sub>T</sub> were used to calculate the current ratings illustrated on page one.
- 3) Figures 3-7 were compiled using these conditions.
- 4) For clamp forces outside these limits, please consult factory.

**Notes on Ratings and Characteristics**

1.0 De-rating Factor

A blocking voltage de-rating factor of 0.13% per °C is applicable to this device for T<sub>j</sub> below 25°C.

2.0 ABCD Constants

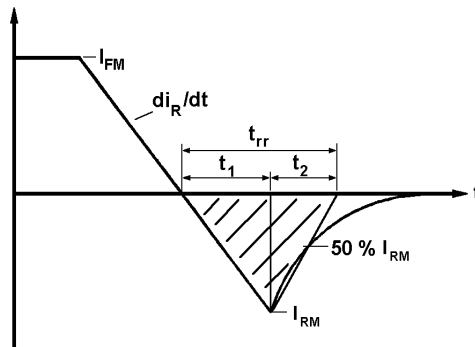
These constants (applicable only over current range of V<sub>F</sub> characteristic in Figure 1) are the coefficients of the expression for the forward characteristic given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

where I<sub>F</sub> = instantaneous forward current.

3.0 Reverse recovery ratings

(i) Q<sub>rr</sub> is based on 50% I<sub>rm</sub> chord as shown in Figure below.



(ii) Q<sub>rr</sub> is based on a 150µs integration time.

i.e.

$$Q_{rr} = \int_0^{150\mu s} i_{rr} \cdot dt$$

(iii)

$$K \text{ Factor} = \frac{t_1}{t_2}$$

#### 4.0 Reverse Recovery Loss

The following procedure is recommended for use where it is necessary to include reverse recovery loss.

From waveforms of recovery current obtained from a high frequency shunt (see Note 1) and reverse voltage present during recovery, an instantaneous reverse recovery loss waveform must be constructed. Let the area under this waveform be E joules per pulse. A new sink temperature can then be evaluated from:

$$T_{SINK} = T_{J(MAX)} - E \cdot [k + f \cdot R_{thJK}]$$

Where k = 0.2314 (°C/W)/s

E = Area under reverse loss waveform per pulse in joules (W.s.)

f = Rated frequency in Hz at the original sink temperature.

R<sub>th(J-Hs)</sub> = d.c. thermal resistance (°C/W)

The total dissipation is now given by:

$$W_{(tot)} = W_{(original)} + E \cdot f$$

##### NOTE 1 - Reverse Recovery Loss by Measurement

This device has a low reverse recovered charge and peak reverse recovery current. When measuring the charge, care must be taken to ensure that:

(a) AC coupled devices such as current transformers are not affected by prior passage of high amplitude forward current.

(b) A suitable, polarised, clipping circuit must be connected to the input of the measuring oscilloscope to avoid overloading the internal amplifiers by the relatively high amplitude forward current signal.

(c) Measurement of reverse recovery waveform should be carried out with an appropriate critically damped snubber, connected across diode anode to cathode. The formula used for the calculation of this snubber is shown below:

$$R^2 = 4 \cdot \frac{V_r}{C_s \cdot di/dt}$$

Where: V<sub>r</sub> = Commutating source voltage

C<sub>s</sub> = Snubber capacitance

R = Snubber resistance

## 5.0 Computer Modelling Parameters

### 5.1 Device Dissipation Calculations

$$I_{AV} = \frac{-V_{T0} + \sqrt{V_{T0}^2 + 4 \cdot ff^2 \cdot r_T \cdot W_{AV}}}{2 \cdot ff^2 \cdot r_T}$$

Where  $V_{T0} = 1.569V$ ,  $r_T = 0.318m\Omega$

$ff$  = form factor (normally unity for fast diode applications)

$$W_{AV} = \frac{\Delta T}{R_{th}}$$

$$\Delta T = T_{j(MAX)} - T_K$$

### 5.2 Calculation of $V_F$ using ABCD Coefficients

The forward characteristic  $I_F$  Vs  $V_F$ , on page 6 is represented in two ways;

- (i) the well established  $V_{T0}$  and  $r_T$  tangent used for rating purposes and
- (ii) a set of constants A, B, C, and D forming the coefficients of the representative equation for  $V_F$  in terms of  $I_F$  given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

The constants, derived by curve fitting software, are given in this report for both hot and cold characteristics. The resulting values for  $V_F$  agree with the true device characteristic over a current range, which is limited to that plotted.

	25°C Coefficients	140°C Coefficients
A	0.9457614	1.1329943
B	0.0566287	-0.02170949
C	$1.66939 \times 10^{-4}$	$7.78189 \times 10^{-5}$
D	$9.156351 \times 10^{-3}$	0.02495673

**Curves**

Figure 1 – Forward characteristics of limit device

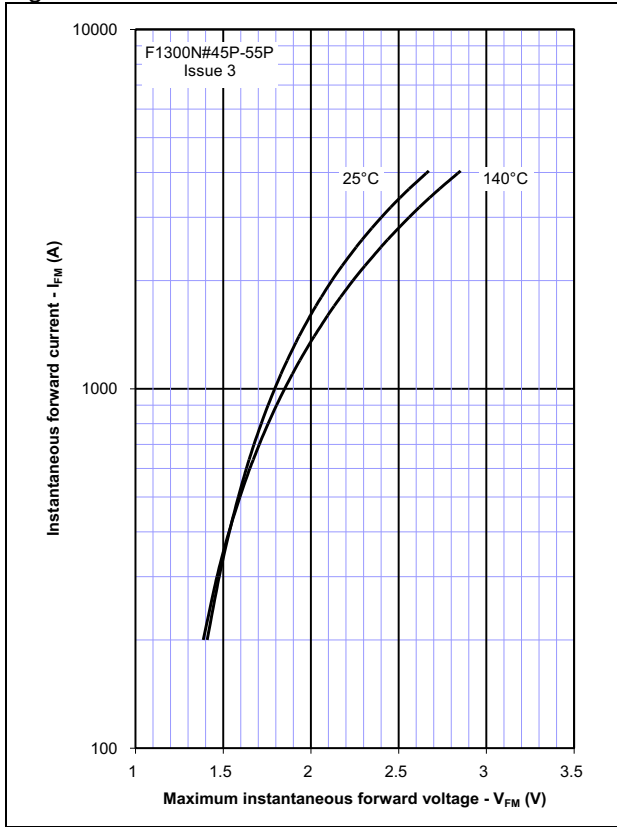


Figure 2 – Maximum forward recovery voltage

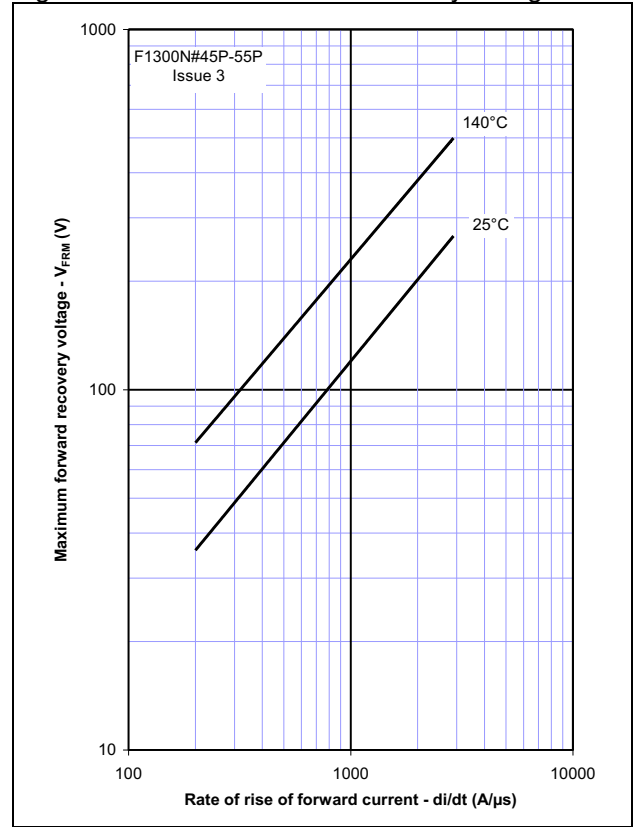


Figure 3 - Recovered charge,  $Q_{rr}$

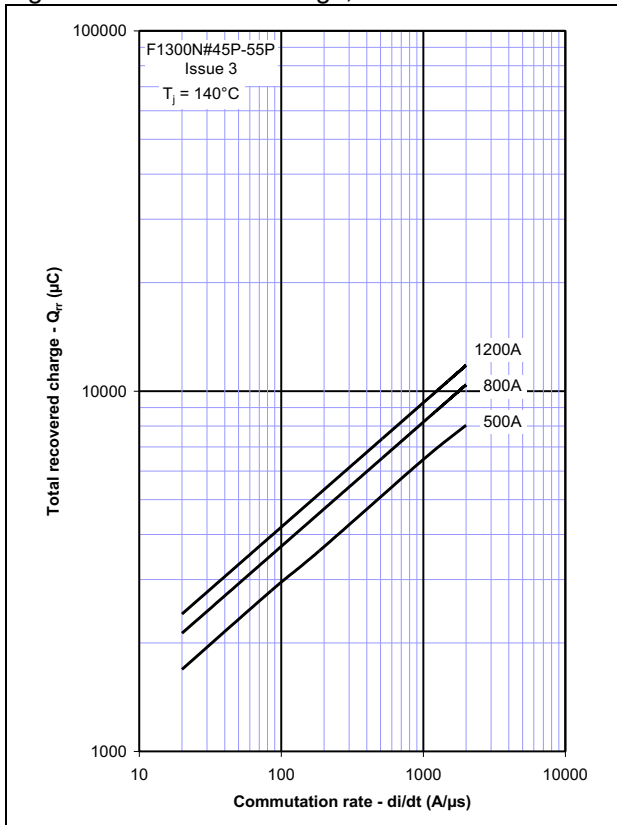


Figure 4 – Recovered charge,  $Q_{ra}$  (50% chord)

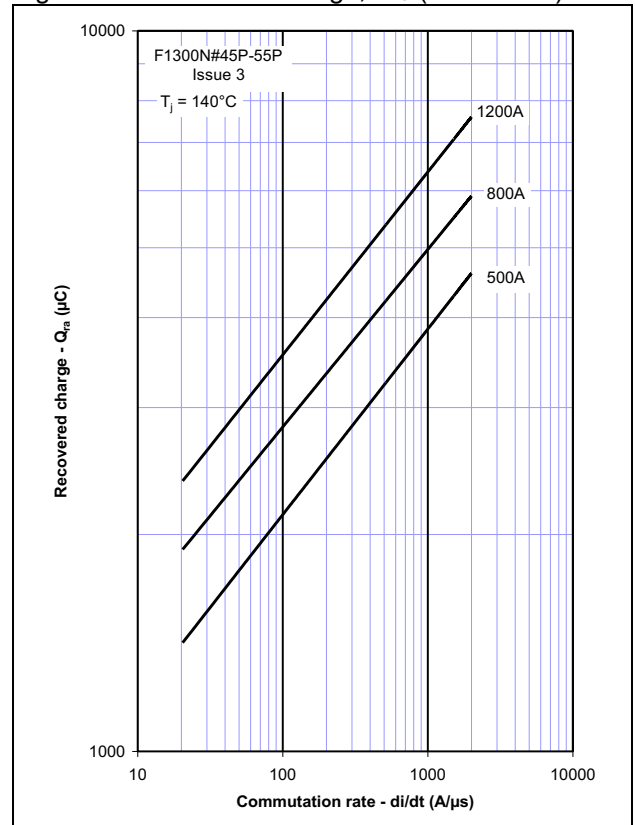


Figure 5 - Maximum reverse current,  $I_{rm}$

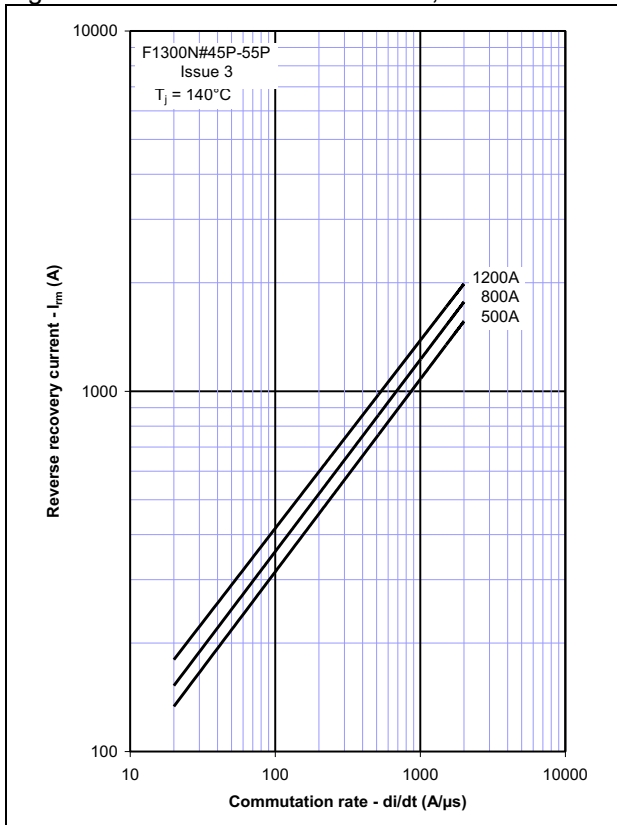


Figure 6 - Maximum recovery time,  $t_{rr}$  (50% chord)

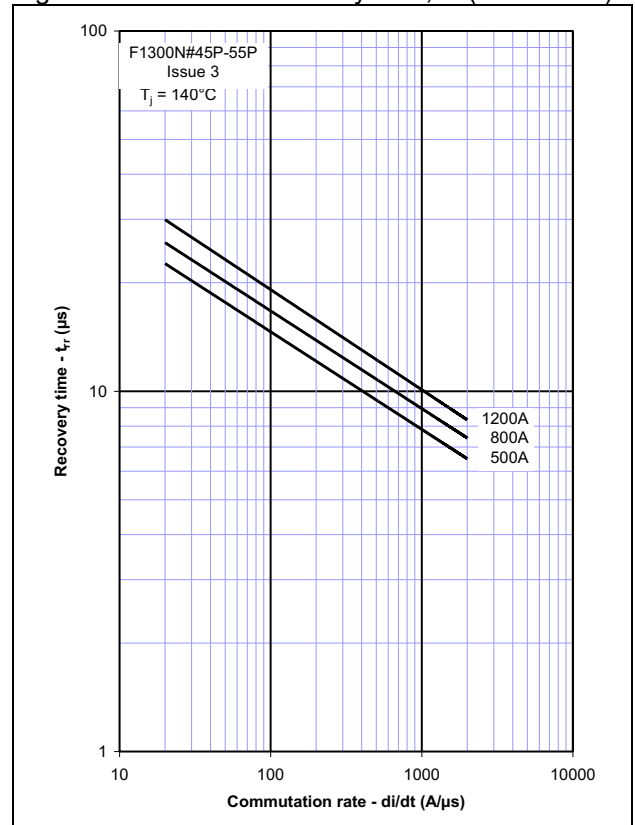


Figure 7 - Reverse recovery energy per pulse

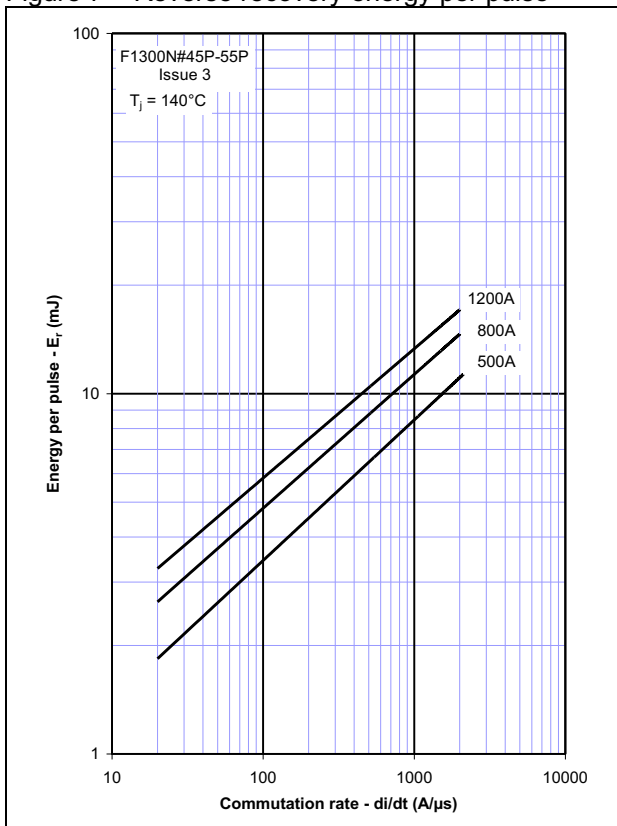


Figure 8 - Sine wave energy per pulse

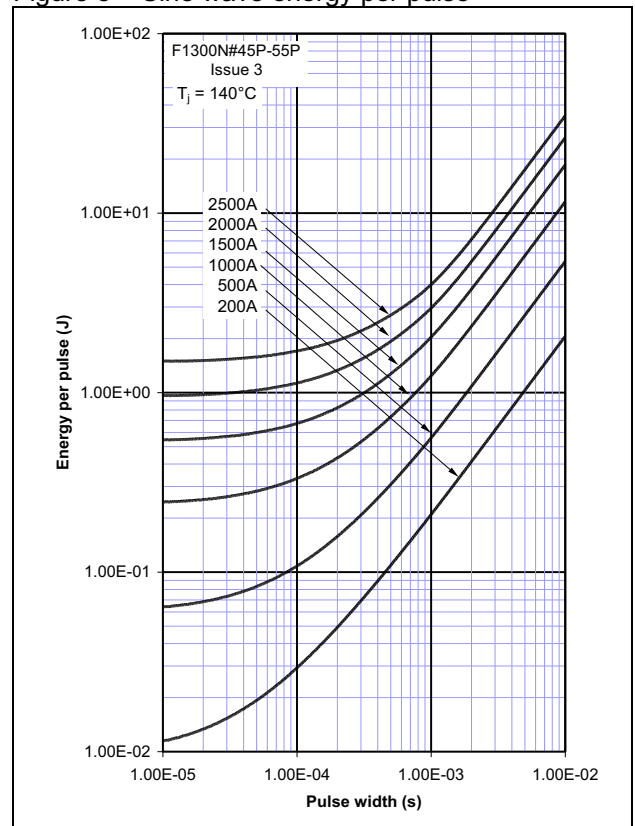


Figure 9 - Sine wave frequency vs. pulse width

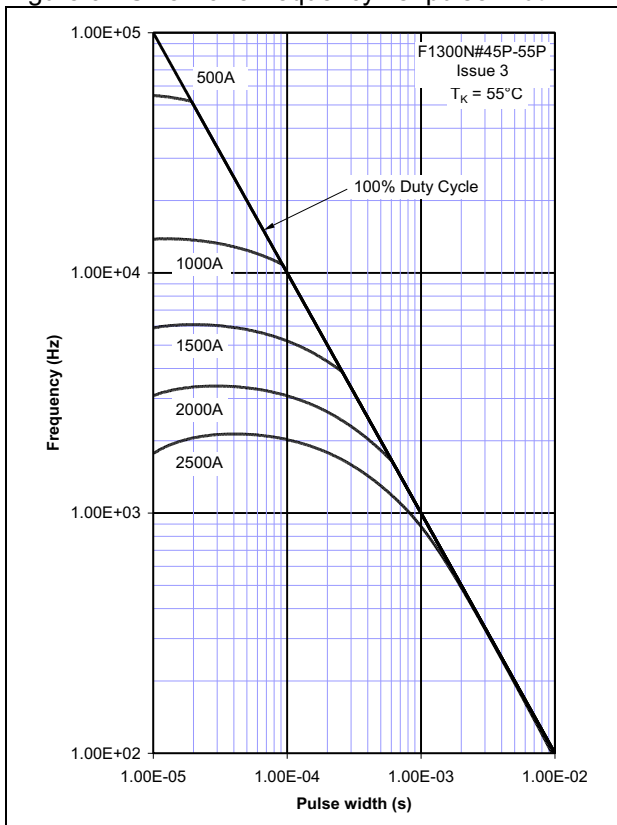


Figure 10 - Sine wave frequency vs. pulse width

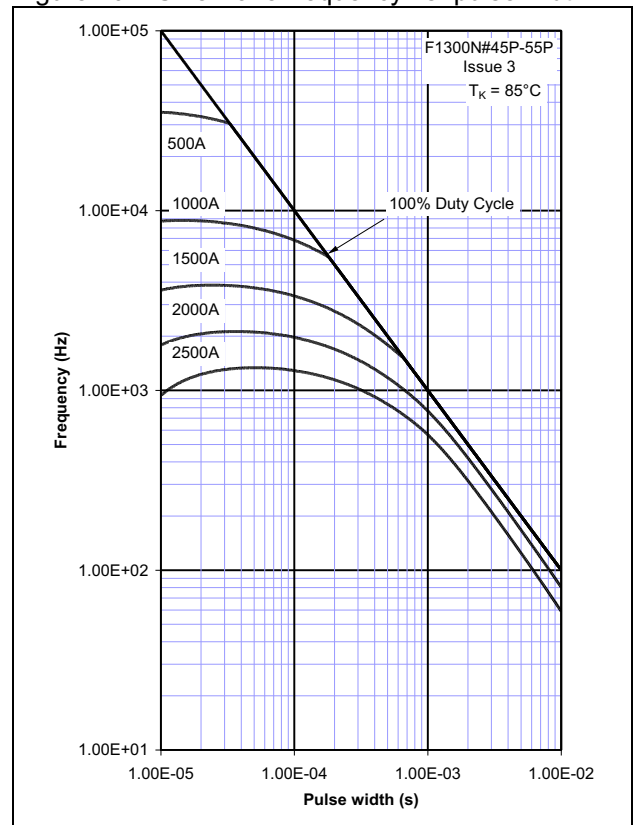


Figure 11 - Square wave energy per pulse

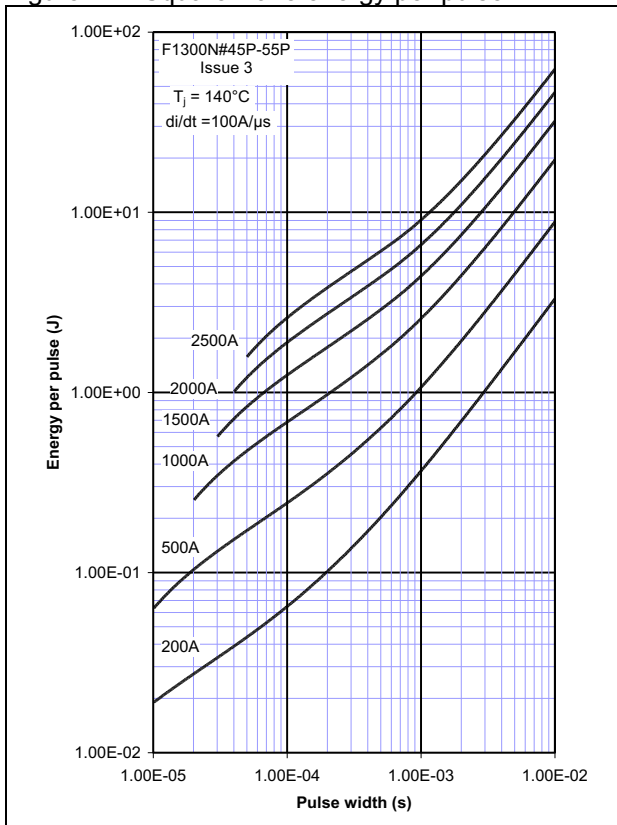


Figure 12 - Square wave energy per pulse

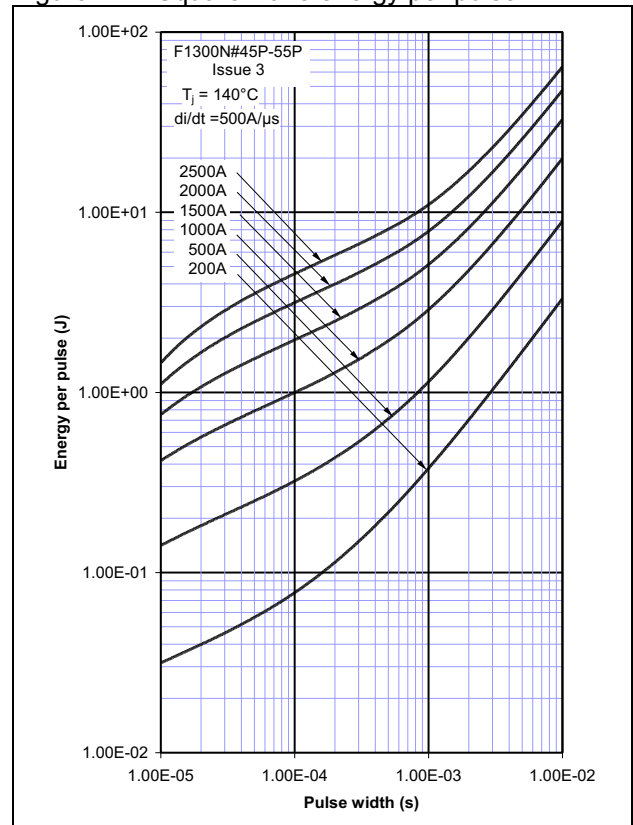




Figure 13 - Square wave frequency vs pulse width

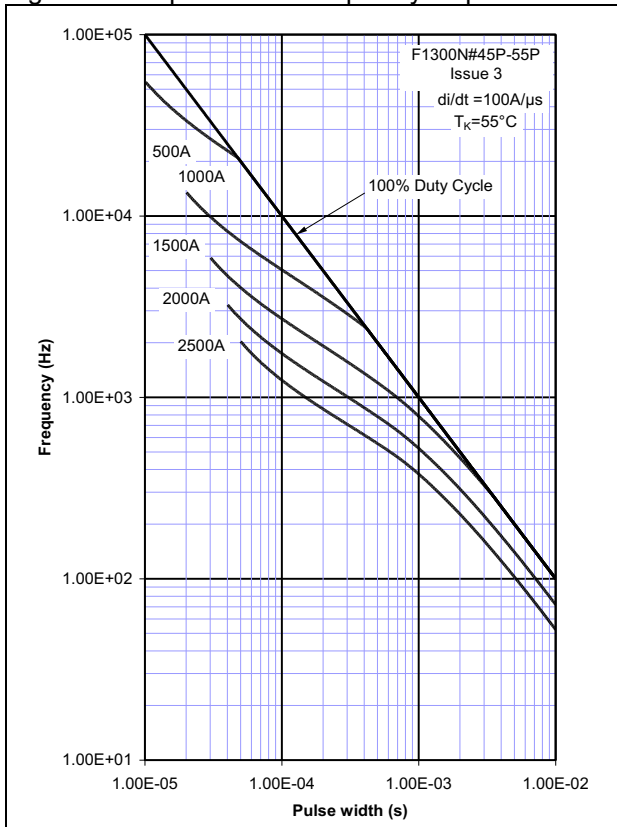


Figure 14 - Square wave frequency vs pulse width

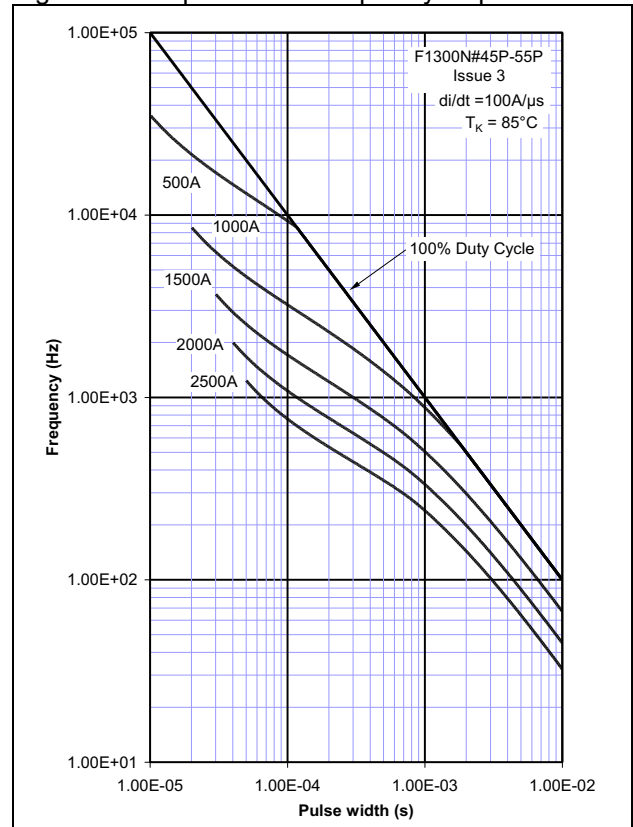


Figure 15 - Square wave frequency vs pulse width

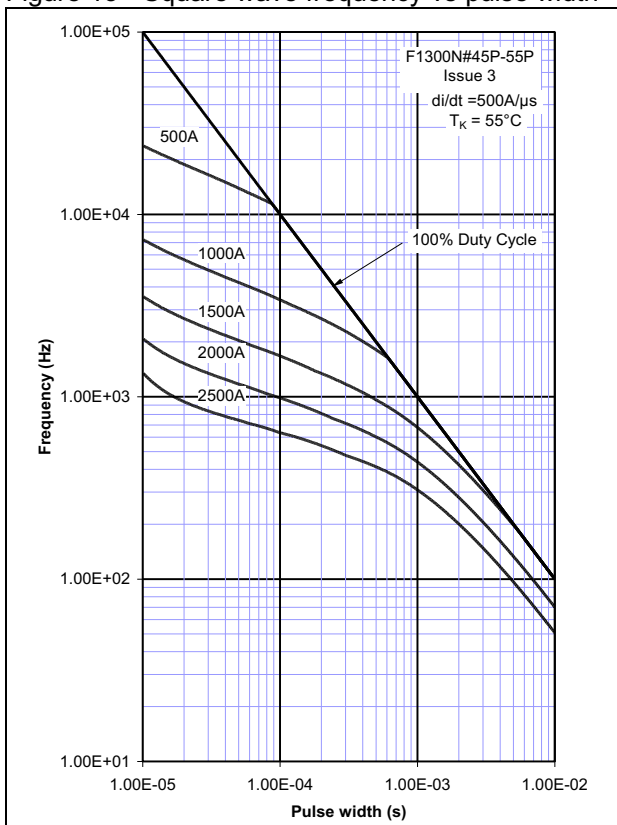


Figure 16 - Square wave frequency vs pulse width

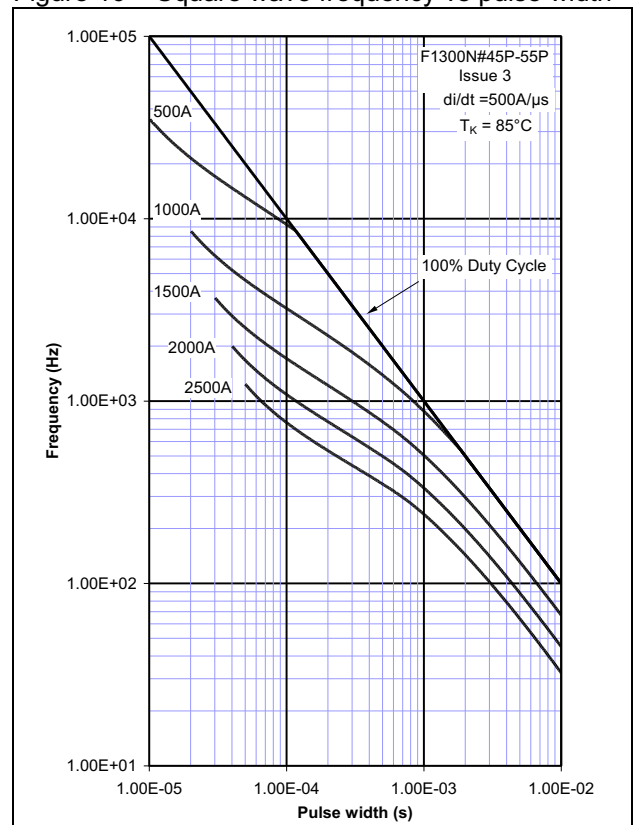


Figure 17 – Maximum surge and  $I^2t$  ratings

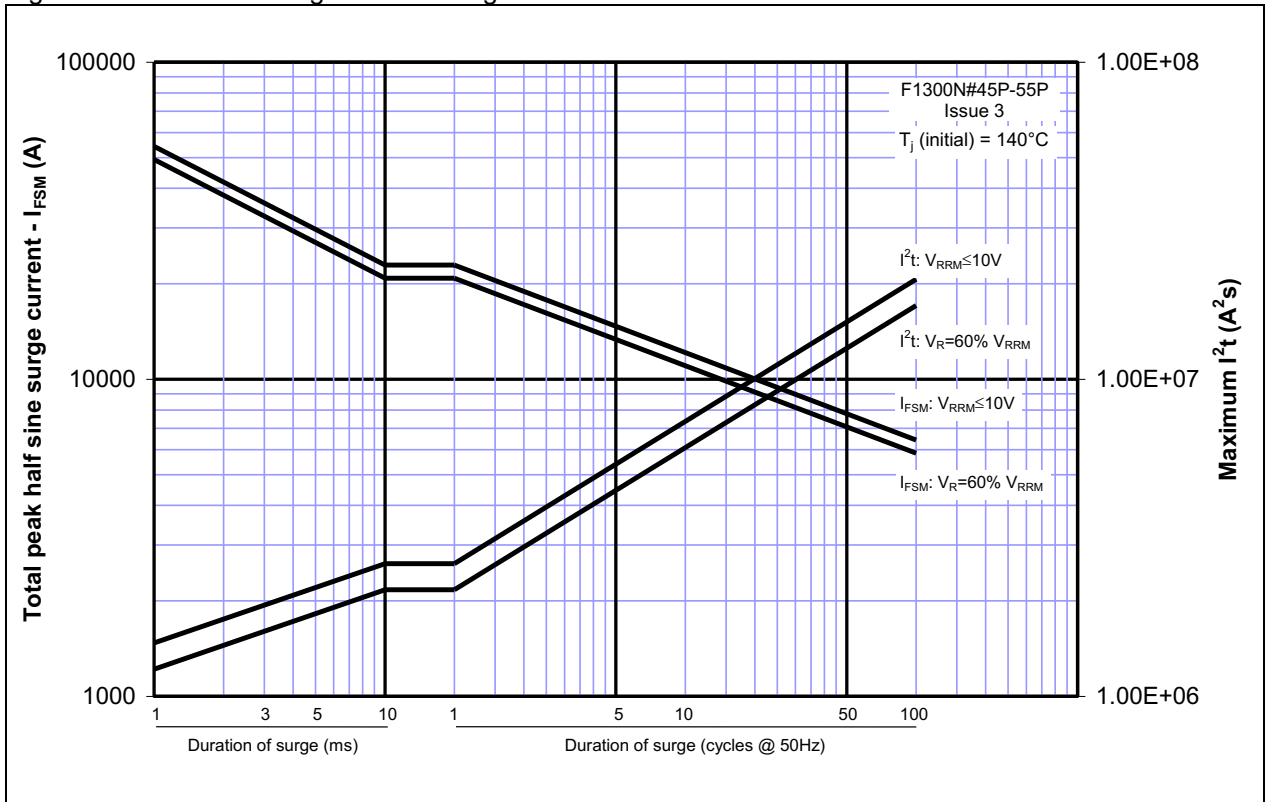
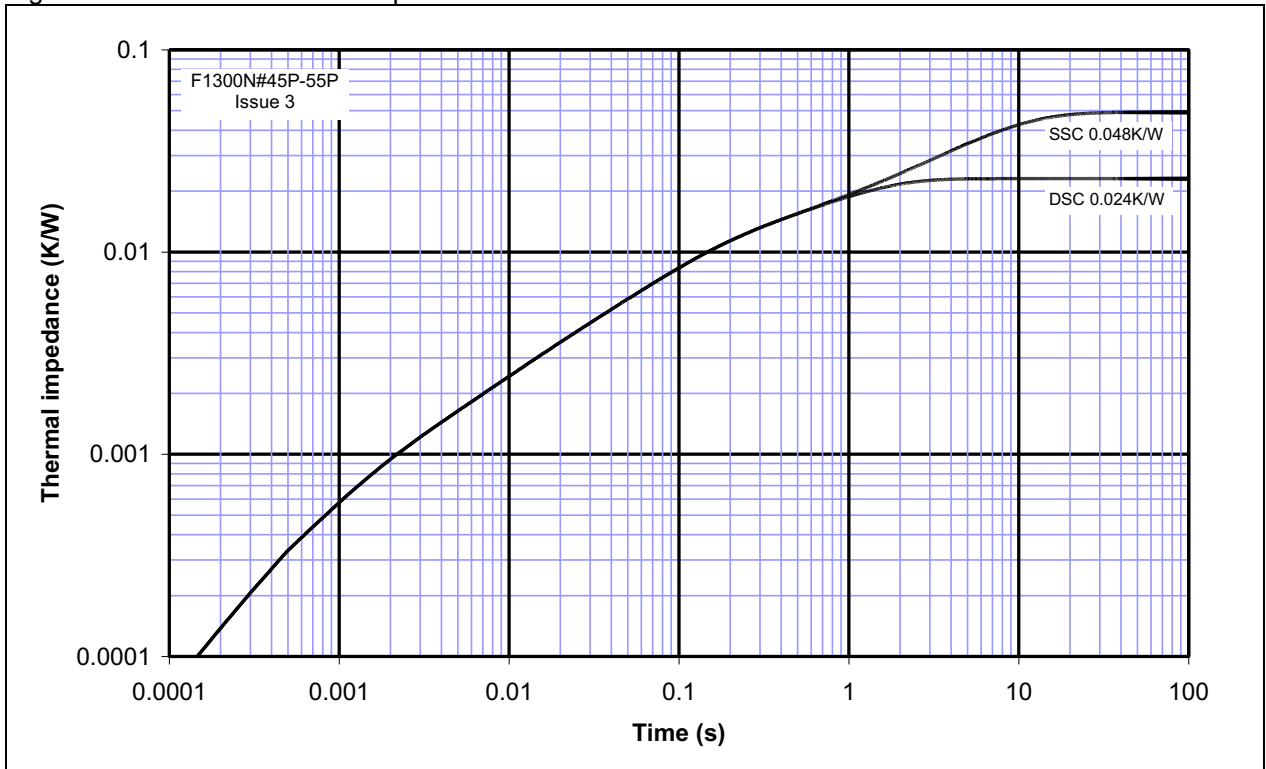
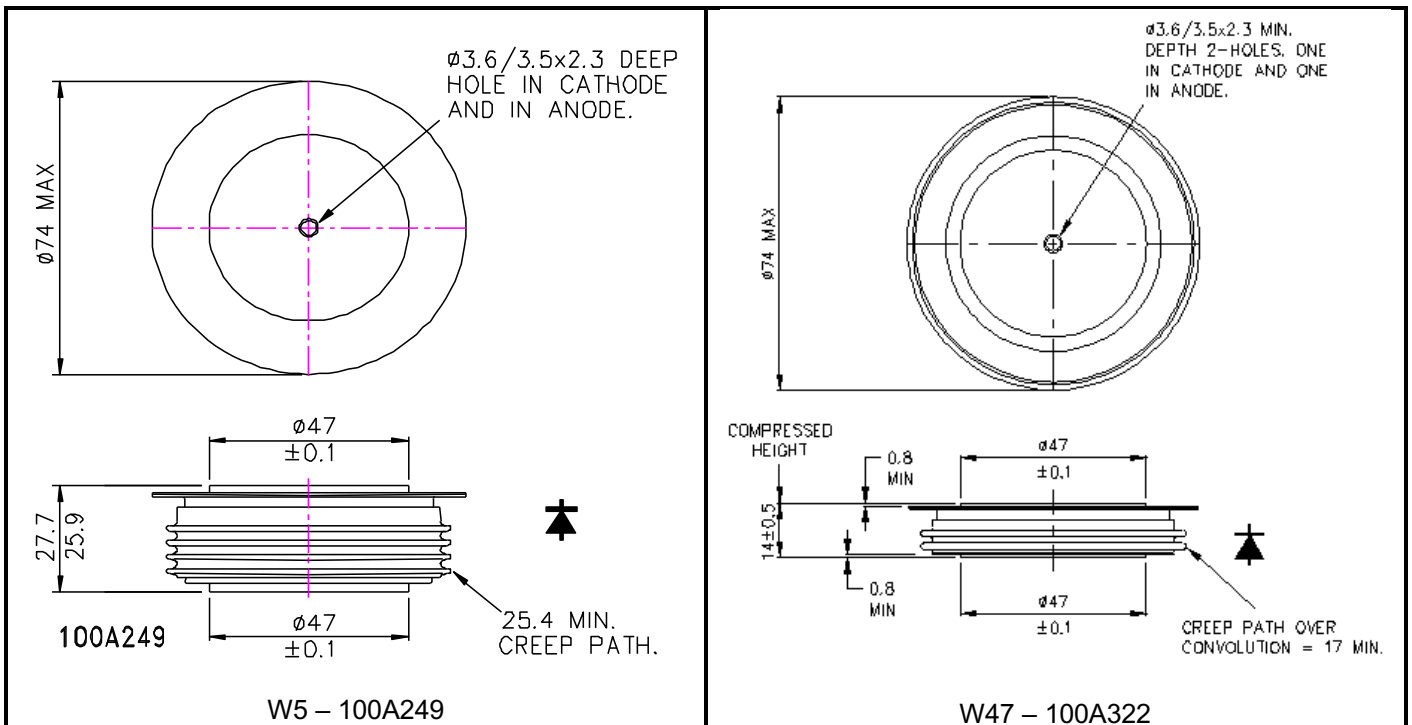


Figure 18 – Transient thermal impedance



**Outline Drawing & Ordering Information**



**ORDERING INFORMATION**

(Please quote 10 digit code as below)

F1300	N#	xx	P
Fixed Type Code	Fixed outline code NC – 27.7mm capsule height NH – 14mm capsule height	Fixed Voltage code $V_{RRM}/100$ 45-55	Fixed code

Order code: F1300N#45P - 4500V  $V_{RRM}$ , 27.7mm clamp height capsule.

**IXYS Semiconductor GmbH**

Edisonstraße 15  
D-68623 Lampertheim  
Tel: +49 6206 503-0  
Fax: +49 6206 503-627  
E-mail: [marcom@ixys.de](mailto:marcom@ixys.de)



**IXYS UK Westcode Ltd**

Langley Park Way, Langley Park,  
Chippenham, Wiltshire, SN15 1GE.  
Tel: +44 (0)1249 444524  
Fax: +44 (0)1249 659448  
E-mail: [sales@ixysuk.com](mailto:sales@ixysuk.com)

**IXYS Corporation**

1590 Buckeye Drive  
Milpitas CA 95035-7418  
Tel: +1 (408) 547 9000  
Fax: +1 (408) 496 0670  
E-mail: [sales@ixys.net](mailto:sales@ixys.net)

[www.ixysuk.com](http://www.ixysuk.com)

[www.ixys.com](http://www.ixys.com)

**IXYS Long Beach, Inc**

IXYS Long Beach, Inc  
2500 Mira Mar Ave, Long Beach  
CA 90815  
Tel: +1 (562) 296 6584  
Fax: +1 (562) 296 6585  
E-mail: [service@ixyslongbeach.com](mailto:service@ixyslongbeach.com)

The information contained herein is confidential and is protected by Copyright. The information may not be used or disclosed except with the written permission of and in the manner permitted by the proprietors IXYS UK Westcode Ltd.

© IXYS UK Westcode Ltd.

In the interest of product improvement, IXYS UK Westcode Ltd reserves the right to change specifications at any time without prior notice.

Devices with a suffix code (2-letter, 3-letter or letter/digit/letter combination) added to their generic code are not necessarily subject to the conditions and limits contained in this report.



---

Disclaimer Notice - Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at [www.littelfuse.com/disclaimer-electronics](http://www.littelfuse.com/disclaimer-electronics).